**Tech Talk** 



## **Quantification of Energy Dispersive Spectrum (EDS)**

#### **Xiaobing Hu**

The NUANCE Center, Northwestern University

Department of Materials Sciences and Engineering, Northwestern University

#### October 21, 2021

Reference book: Transmission Electron Microscopy—A Textbook for Materials Science written by David B. Williams and C. Barry Carter





## > Acquisition of high-quality EDS dataset

## Procedures of EDS quantification

## > Why EDS quantification is inaccurate?





## **Acquisition of high-quality EDS dataset**

#### Tips and tricks for EDS acquisition

- Maximize probe current if the sample can endure high dose (maximize the generated X-rays)
- Tilt your sample to around 10-15 $^{\circ}$  to face the detector (maximize the collection efficiency)
- Do not forget to remove the objective aperture (reduce artifact)
- Tilt your sample to avoid the two-beam condition (reduce the channeling effect)
- Use a shorter time constant ( $\tau \simeq$  5-100  $\mu s)\,$  to maximize the counting rate
- Regions cannot be too thick (> 600 nm) or too thin (< 50nm)
- Dead time cannot be too large (> 50-60%) or too small (< 3%)
- Your sample should not have carbon contamination





## **Procedures of EDS quantification**

**Concept of EDS quantification and Cliff-Lorimer ratio method** 

$$\frac{C_A}{C_B} = k_{AB} \frac{I_A}{I_B}$$
 and  $C_A + C_B = 1$ 

 $C_A/C_B$  : atomic percentage or weight percentage of elements A/B;

 $I_A / I_B$ : EDS peak intensity of elements A/B;

 $k_{AB}$ : not a constant but related to the following three parameters:

a> Z, the atomic number

b> A, the absorption of X-rays within the sample

c> F, the fluorescence of X-rays within the specimen

Thin-foil criterion: For TEM samples, we usually assume that the specimen is thin enough to

ignore the absorption and fluorescence.





## **Procedures of EDS quantification**

#### **Steps of EDS quantification**

- Identification of each peak
- Remove background
- Peak integration
- How to obtain the  $k_{AB}$ ? (Standard sample or calculation method)

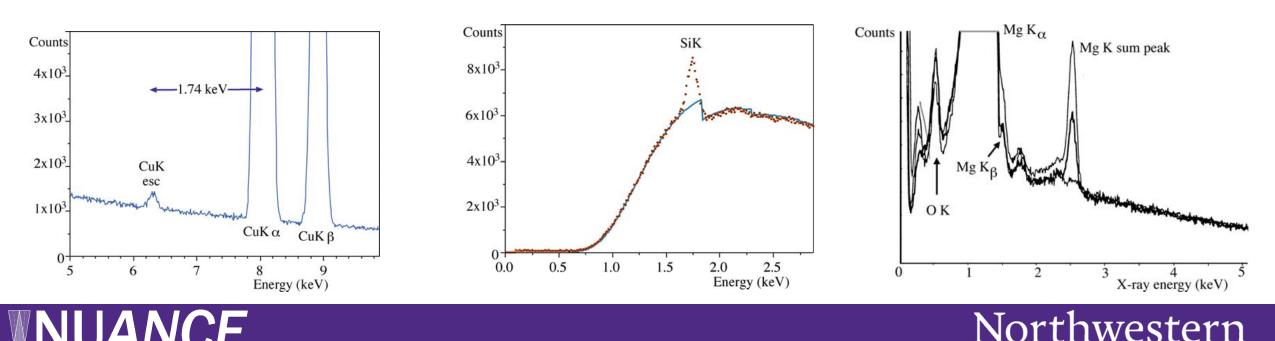




Si escape peak (signal detection artifact)

Detector is not a perfect sink. Incoming photon with energy E is not transformed into electronhole pairs but fluoresces a Si Kα X-ray with a 1.74k eV energy.

- Internal fluorescence peak (signal detection artifact)
  Incoming photons fluoresce atoms in the dead layer of the detector and result in Si Kα peak
- Sum peak (signal processing artifact)
  Sum peak occurs when the count rate exceeds the electronics' ability to discriminate all the individual pulses and so-called 'pulse pile-up'. Reduce the dead time!!



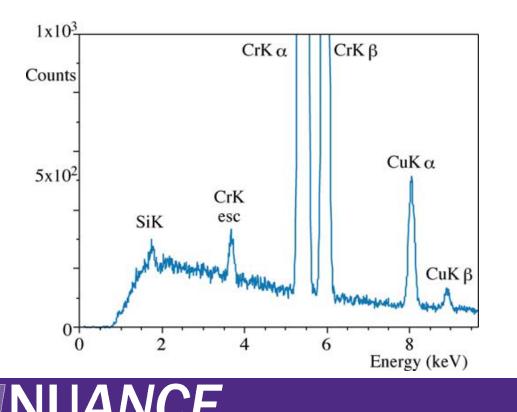


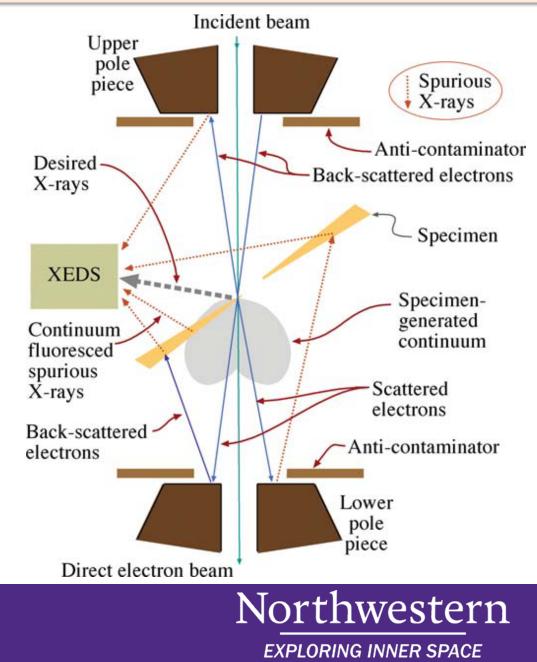
#### System X-rays

Cu is everywhere

Nanoscale Characterization Experimental Cente

- Remember to remove the objective aperture before taking EDS signal
- Operate as close to zero tilt as possible



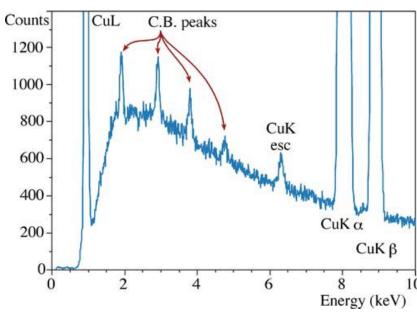


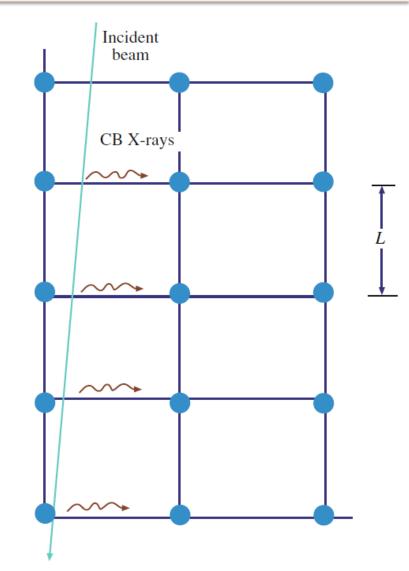
#### **Coherent Bremsstrahlung (CB)**

- Continuous bremsstrahlung spectrum usually happens bulk polycrystalline materials by electrons with lower energy (< 30 ekV)
- Within TEM, for single crystalline specimens, CB likely will occur.

$$\mathsf{E}_{\mathsf{CB}} = \frac{12.4\beta}{L(1 - \beta \cos(90 + \alpha))}$$

- β: electron velocity divided by the velocity of light
- L: Lattice spacing in the beam direction
- $\boldsymbol{\alpha} {:} take-off$  angle of the detector

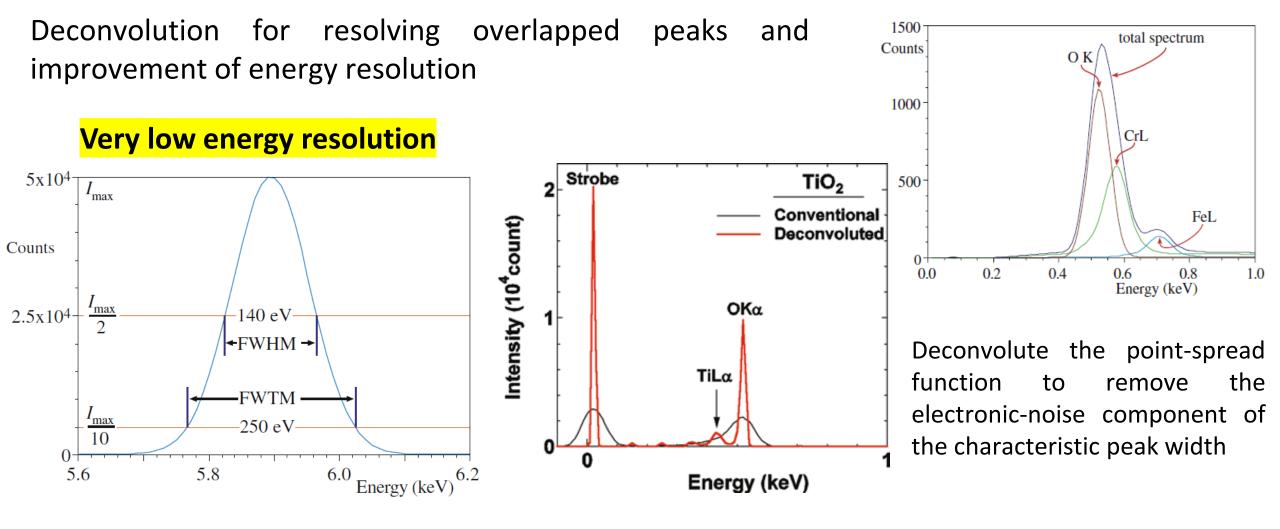








#### Deconvolution overlap



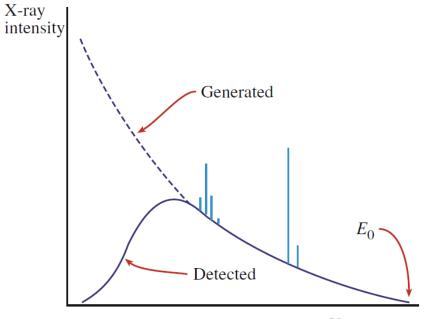




## **Procedures of EDS quantification—Remove background**

- Bremsstrahlung X-rays (braking radiation)
- When electrons interact with the Coulomb field of nucleus, there will be substantial momentum changes and it may emit an X-ray during this process.
- The approximate expression used is:  $N(E) = \frac{KZ(E_0 - E)}{E}$
- N(E): number of bremsstrahlung photons with energy E;
- Z: atomic number; E<sub>0</sub>: electron energy
- K: Kramers' constant including Kramer's original constant,
- collection efficiency and processing efficiency of detector,
- absorption of X-rays within specimen







Northwestern

EXPLORING INNER SPACE

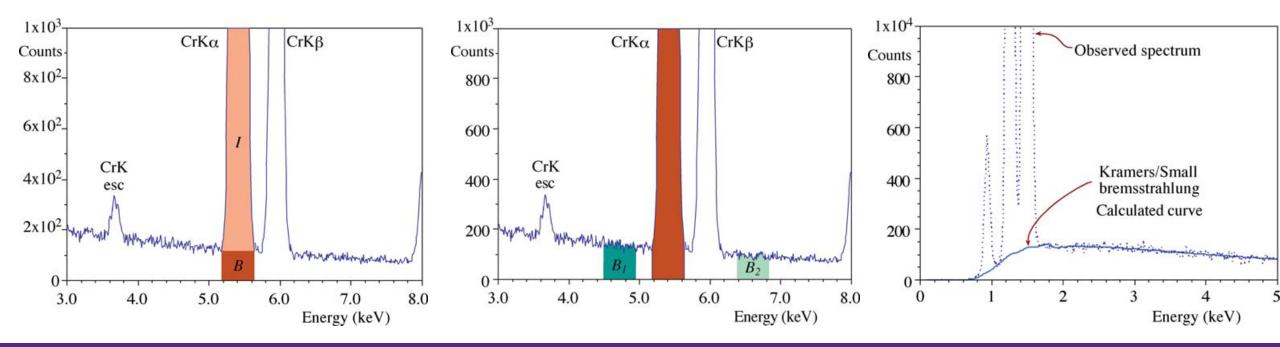
## **Procedures of EDS quantification—Remove background**

#### a> Window methods

Simple but no physical meaning; optimum window width is 1.2 FWHM;

#### **b> modeling the background**

At low-energy region, peak overlap and absorption are strong; Modeling background is a better solution



Northwestern

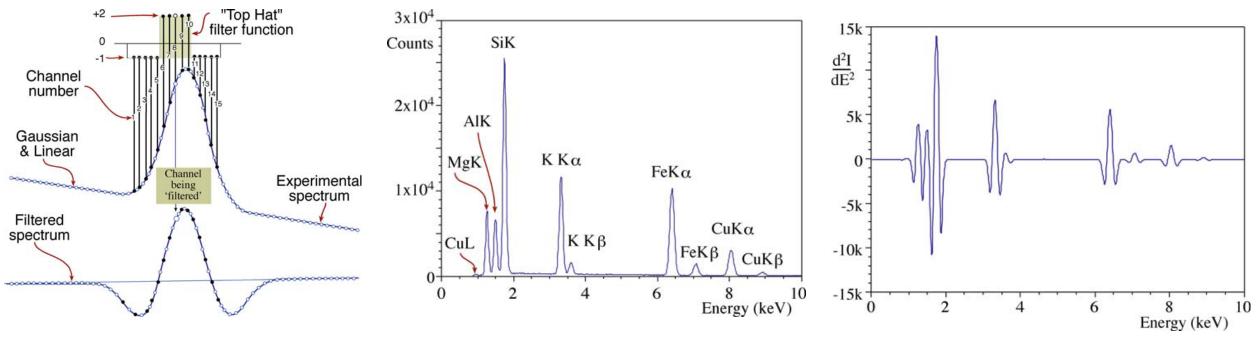
EXPLORING INNER SPACE



## **Procedures of EDS quantification—Remove background**

- c> Filtering out the background (Top-hat filter)
- no physical meaning;
- The characteristic peaks show a rapid variation of counts as a function of energy  $\left(\frac{dI}{dE}\right)$  is large;

Background has a relatively small  $\frac{dI}{dE} \left( \frac{d^2I}{d^2E} \sim 0 \right)$ 



Northwestern

EXPLORING INNER SPACE



## **Procedures of EDS quantification--Peak integration**

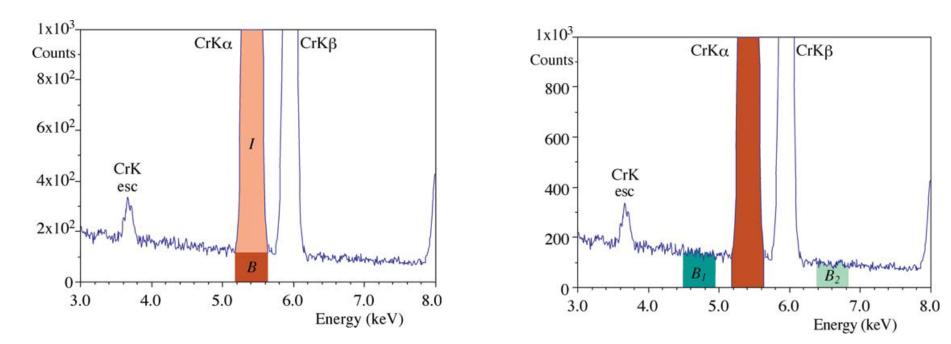
a> Window methods

Remember to use the same window width as background subtraction

b> modeling the background and filtering background

Fit the peaks using a slightly modified Gaussian function and intergrade the counts under the

Gaussian







## Procedures of EDS quantification—Determination of $k_{AB}$

- How to obtain the  $k_{AB}$ ?
- a> Experimental determination
- \*Use standard sample with the required elements and known chemical compositions (not easy to find;);
- \*Make sure using the sample experimental parameters and processing parameters as the ones for your samples
- b> Theoretical calculation

$$k_{AB} = \frac{(Qwa)_A A_B \varepsilon_A}{(Qwa)_B A_A \varepsilon_B}$$

 $A_A, A_B$ : atomic weight  $Q_A, Q_B$ : ionization cross sections  $w_A, w_B$ : fluorescence yield  $a_A, a_B$ : relative transition probability  $\varepsilon_A, \varepsilon_B$ :: detector efficiency **NUANCE** 



## **Procedures of EDS quantification-- ζ-factor method**

#### **Concept of EDS quantification and ζ-factor method**

$$(\rho t)_A = \zeta_A \frac{I_A}{C_A}$$
  $\zeta_A = \frac{A}{C_A N_0 Q wai}$   $C_A + C_B = 1$ 

 $\frac{c_A}{C_B} = \frac{I_A \zeta_A}{I_B \zeta_A}$  and  $C_A / C_B$ : atomic percentage or weight percentage of elements A/B;

- $I_A/I_B$ : EDS peak intensity of elements A/B
- i: beam current;  $N_0$ : Avogadro's constant; Q: ionization cross section; w: fluorescence yield
- a: relative transition probability
- Advantage: preparation of standard sample is easy; pure-element with known composition





### Why EDS quantification is inaccurate?

Statistics error

$$\left(\frac{\sigma_C}{C_A/C_B}\right)^2 = \left(\frac{\sigma_{k_{AB}}}{k_{AB}}\right)^2 + \left(\frac{\sigma_{I_A}}{I_A}\right)^2 + \left(\frac{\sigma_{I_B}}{I_B}\right)^2$$

Relative Error =  $\frac{3\sigma}{N} * 100\% = \frac{3N^{0.5}}{N} * 100\%$ 

Increasing the total counts and multiple measurement points are ways to reduce the statistics error.

This error exists for both calculated  $k_{AB}$  or experimentally determined  $k_{AB}$ 





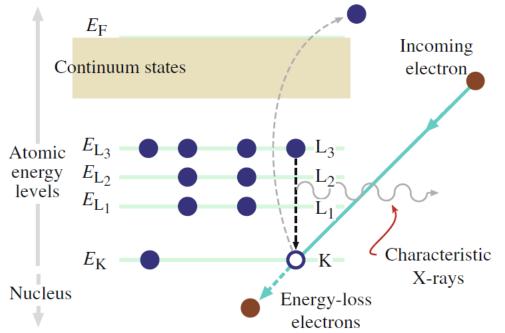
## Why EDS quantification is inaccurate?

- Absorption and fluorescence
- An ionized atom does not have to lose energy by giving off a characteristic X-ray but can emit an Auger electron instead.
- Fluorescence yield ( $\omega$ ) describes the probability of Xray versus Auger emission.  $\omega = \frac{Z^4}{a+Z^4}$  (for K shell, a ~10<sup>6</sup>)

For C-K edge, 
$$\omega \sim 10^{-3}$$
;

```
For Ge-K edge, \omega \sim 0.5;
```

That's also why EDS is not the best way to analyze the light elements such as Li, Be and B.







## Why EDS quantification is inaccurate?

- Significant peak overlap
- For calculated  $k_{AB}$ , the calculation of ionization cross sections Q is inaccurate particularly for L, M lines (calculation error no better than  $\pm 10 20\%$ )
- $\succ$  For calculated  $k_{AB}$ , detector efficiency  $\varepsilon$  is difficult to accurately determined
- > For experimental determination, it is difficult to prepare the standard sample
- Possible sample degeneration and contamination under electron beam
- Inaccurate background subtraction and peak integration





## Thank you for your attention!

# Q.&A.



